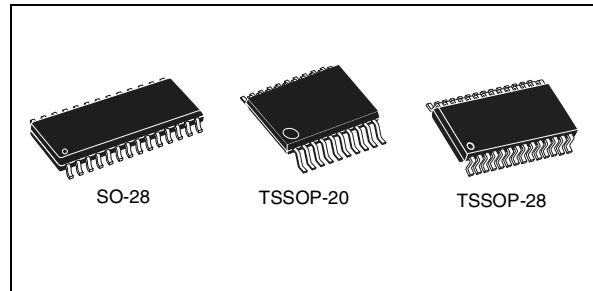


### Features

- Designed to be compatible with the NDS conditional access system (except ST8024LTR)
- ISO 7816, GSM11.11 and EMV 4.2 (payment systems) compatible
- IC card interface
- 3 V or 5 V supply for the ST8024L device ( $V_{DD}$ )
- Three specifically protected half-duplex bi-directional buffered I/O lines to card contacts C4, C7 and C8
- Step-up converter for  $V_{CC}$  generation separately powered by a  $5\text{ V} \pm 20\%$  supply ( $V_{DDP}$  and PGND)
- $1.8\text{ V} \pm 6.5\%$ ,  $3\text{ V}$  or  $5\text{ V} \pm 5\%$  regulated card supply voltage ( $V_{CC}$ ) with appropriate decoupling has the following capabilities:
  - $I_{CC} < 80\text{ mA}$  at  $V_{DDP} = 4.75\text{ to }6.5\text{ V}$
  - Handles current spikes of  $40\text{ nA}$  up to  $20\text{ MHz}$
  - Controls rise and fall times
  - Filtered overload detection at  $\sim 120\text{ mA}$
- Thermal and short-circuit protection on all card contacts
- Automatic activation and deactivation sequences; initiated by software or by hardware in the event of a short-circuit, card take-off, overheating,  $V_{DD}$  or  $V_{DDP}$  dropout



- Enhanced ESD protection on card side ( $>6\text{ kV}$ )
- $26\text{ MHz}$  integrated crystal oscillator
- Built-in debounce on card presence contacts
- One multiplexed status signal  $\overline{OFF}$
- Non-inverted control of RST via pin RSTIN
- Clock generation for cards up to  $20\text{ MHz}$  (divided by 1, 2, 4 or 8 through CLKDIV1 and CLKDIV2 signals) with synchronous frequency changes
- Supply supervisor for spike-killing during power-on and power-off and power-on reset (threshold fixed internally or externally by a resistor divider)

### Applications

- Smartcard readers for set-top boxes
- IC card readers for banking
- Identification, pay TV

**Table 1. Device summary**

Order code	PORADJ/ 1.8 V function	Temperature range	Package	Packaging	Package top mark
ST8024LCDR <sup>(1)</sup>	PORADJ	$-25\text{ to }85\text{ }^{\circ}\text{C}$	SO-28 (tape and reel)	1000 parts per reel	ST8024LC
ST8024LCTR <sup>(1)</sup>	PORADJ	$-25\text{ to }85\text{ }^{\circ}\text{C}$	TSSOP-28 (tape and reel)	2500 parts per reel	ST8024LC
ST8024LACDR <sup>(1)</sup>	1.8 V	$-25\text{ to }85\text{ }^{\circ}\text{C}$	SO-28 (tape and reel)	1000 parts per reel	ST8024LAC
ST8024LTR	1.8 V	$-25\text{ to }85\text{ }^{\circ}\text{C}$	TSSOP-20 (tape and reel)	2500 parts per reel	ST8024L
ST8024LACTR <sup>(1)</sup>	1.8 V	$-25\text{ to }85\text{ }^{\circ}\text{C}$	TSSOP-28 (tape and reel)	2500 parts per reel	ST8024LAC

1. Certified by NDS.

# Contents

<b>1</b>	<b>Description</b> .....	<b>5</b>
<b>2</b>	<b>Diagram</b> .....	<b>6</b>
<b>3</b>	<b>Pin configuration</b> .....	<b>7</b>
<b>4</b>	<b>Maximum ratings</b> .....	<b>9</b>
<b>5</b>	<b>Electrical characteristics</b> .....	<b>10</b>
<b>6</b>	<b>Functional description</b> .....	<b>18</b>
6.1	Power supply .....	18
6.2	Voltage supervisor .....	18
6.2.1	Without external divider on pin PORADJ .....	18
6.2.2	With an external divider on pin PORADJ .....	19
6.2.3	Application examples .....	19
6.3	Clock circuitry (only on SO-28 and TSSOP-28 packages) .....	20
6.4	I/O transceivers .....	21
6.5	Inactive mode .....	21
6.6	Activation sequence .....	21
6.7	Active mode .....	23
6.8	Deactivation sequence .....	23
6.9	V <sub>CC</sub> generator .....	24
6.10	Fault detection .....	25
6.11	V <sub>CC</sub> selection settings .....	26
<b>7</b>	<b>Applications</b> .....	<b>27</b>
<b>8</b>	<b>Package mechanical data</b> .....	<b>28</b>
<b>9</b>	<b>Revision history</b> .....	<b>34</b>

## List of tables

Table 1.	Device summary . . . . .	1
Table 2.	Pin description . . . . .	7
Table 3.	Absolute maximum ratings . . . . .	9
Table 4.	Thermal data. . . . .	9
Table 5.	Recommended operating conditions . . . . .	9
Table 6.	Electrical characteristics over recommended operating condition . . . . .	10
Table 7.	Step-up converter . . . . .	11
Table 8.	Card supply voltage characteristics . . . . .	11
Table 9.	Crystal connection (pins XTAL1 and XTAL2) . . . . .	12
Table 10.	Data lines (pins I/O, I/OUC, AUX1, AUX2, AUX1UC, and AUX2UC) . . . . .	12
Table 11.	Data lines to card reader (pins I/O, AUX1, and AUX2 with integrated 11 k $\Omega$ pull-up resistor to V <sub>CC</sub> ) . . . . .	13
Table 12.	Data lines to microcontroller (pins I/OUC, AUX1UC, and AUX2UC with integrated 11 k $\Omega$ pull-up resistor to V <sub>DD</sub> ) . . . . .	14
Table 13.	Internal oscillator. . . . .	14
Table 14.	Reset output to card reader (pin RST) . . . . .	14
Table 15.	Clock output to card reader (pin CLK) . . . . .	15
Table 16.	Control inputs (pins CLKDIV1, CLKDIV2, $\overline{\text{CMDVCC}}$ , RSTIN, 5V/3V and PORADJ/1.8V) . . . . .	15
Table 17.	Card presence inputs (pins PRES and $\overline{\text{PRES}}$ ) . . . . .	16
Table 18.	Interrupt output (pin OFF NMOS drain with integrated 20 k $\Omega$ pull-up resistor to V <sub>DD</sub> ) . . . . .	16
Table 19.	Protection and limitation . . . . .	16
Table 20.	Timing . . . . .	16
Table 21.	Clock frequency selection. . . . .	20
Table 22.	Card presence indicator . . . . .	22
Table 23.	V <sub>CC</sub> selection settings. . . . .	26
Table 24.	SO-28 small outline, package mechanical data . . . . .	28
Table 25.	TSSOP-20 package mechanical data. . . . .	29
Table 26.	TSSOP-28 package mechanical data. . . . .	30
Table 27.	SO-28 tape and reel mechanical data . . . . .	31
Table 28.	TSSOP-20 tape and reel mechanical data . . . . .	32
Table 29.	TSSOP-28 tape and reel mechanical data . . . . .	33
Table 30.	Document revision history . . . . .	34

## List of figures

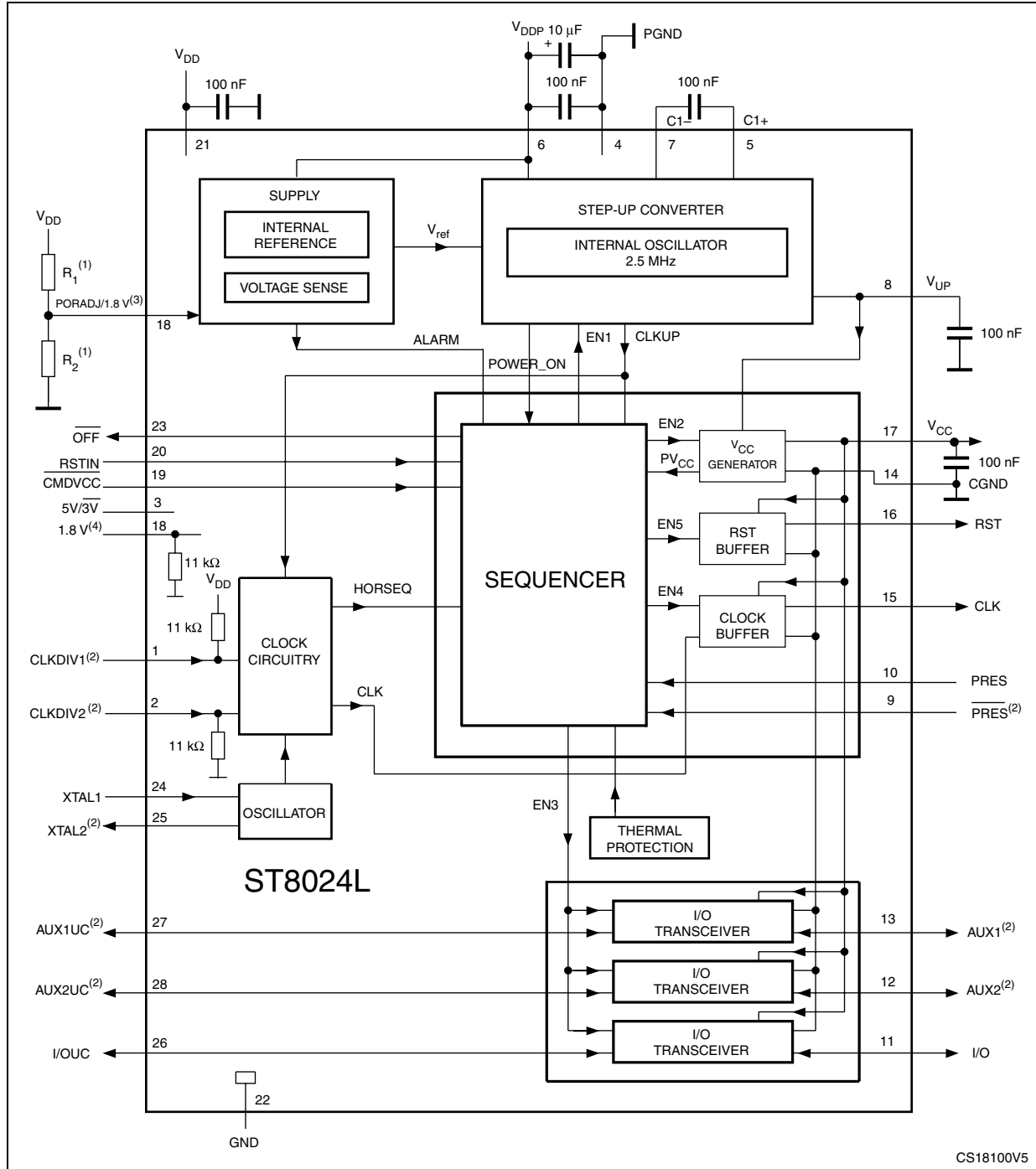
Figure 1.	Block diagram . . . . .	6
Figure 2.	Pin connections . . . . .	7
Figure 3.	Definition of output and input transition times . . . . .	17
Figure 4.	Voltage supervisor . . . . .	19
Figure 5.	Activation sequence using RSTIN and $\overline{\text{CMDVCC}}$ . . . . .	22
Figure 6.	Activation sequence at $t_3$ . . . . .	23
Figure 7.	Deactivation sequence . . . . .	24
Figure 8.	Behavior of $\overline{\text{OFF}}$ , $\overline{\text{CMDVCC}}$ , PRES, and $V_{\text{CC}}$ . . . . .	25
Figure 9.	Emergency deactivation sequence (card extraction) . . . . .	26
Figure 10.	Hardware hookup . . . . .	27
Figure 11.	SO-28 small outline, package mechanical drawing . . . . .	28
Figure 12.	TSSOP-20 package mechanical drawing . . . . .	29
Figure 13.	TSSOP-28 package mechanical drawing . . . . .	30
Figure 14.	SO-28 tape and reel schematic . . . . .	31
Figure 15.	TSSOP-20 tape and reel schematic . . . . .	32
Figure 16.	TSSOP-28 tape and reel schematic . . . . .	33

# 1 Description

The ST8024L is a complete low-cost analog interface for asynchronous Class A, B, and C smartcards. It can be placed between the card and the microcontroller with few external components to perform all supply protection and control functions. The ST8024LCDR and ST8024LCTR are compatible with the ST8024 (with the exception of  $V_{th(ext)rise/fall}$  value).

## 2 Diagram

Figure 1. Block diagram



1. To be used with the PORADJ pin if needed.
2. Not available in the TSSOP-20L package.
3. ST8024LCDR, ST8024LCTR.
4. ST8024LACDR, ST8024LACTR, ST8024LTR.

### 3 Pin configuration

Figure 2. Pin connections

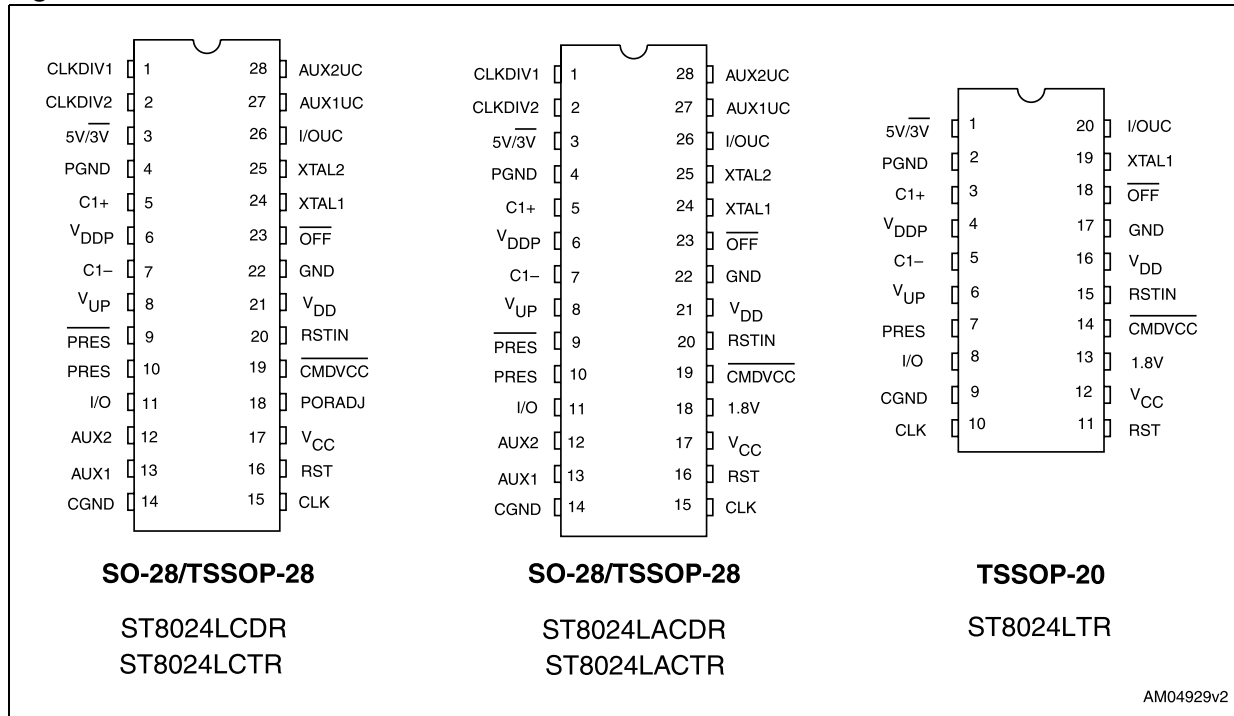


Table 2. Pin description

Symbol	Name and function	SO-28/ TSSOP-28	TSSOP-20
CLKDIV1	Control of CLK frequency (internal 11 kΩ pull-up resistor connected to V <sub>DD</sub> )	1	N. A.
CLKDIV2	Control of CLK frequency (internal 11 kΩ pull-down resistor connected to GND)	2	N. A.
5V/3V	5 V or 3 V V <sub>CC</sub> selection for communication with the smartcard. Logic high selects 5 V operation and logic low selects 3 V operation (for ST8024LCADR, ST8024LACTR, and ST8024LTR: if the 1.8V pin is logic high, the 5V/3V pin is a "don't care"). See <a href="#">Table 23</a> for a description of the V <sub>CC</sub> selection settings.	3	1
PGND	Power ground for step-up converter	4	2
C1+	External capacitor step-up converter	5	3
V <sub>DDP</sub>	Power supply for step-up converter	6	4
C1-	External capacitor step-up converter	7	5
V <sub>UP</sub>	Output of step-up converter	8	6
$\overline{\text{PRES}}$	Card presence input (active low) - bonding option	9	N. A.
PRES	Card presence input (active high)	10	7
I/O	Data line to and from card (C7) (internal 11 kΩ pull-up resistor connected to V <sub>CC</sub> )	11	8

Table 2. Pin description (continued)

Symbol	Name and function	SO-28/ TSSOP-28	TSSOP-20
AUX2	Auxiliary line to and from card (C8) (internal 11 k $\Omega$ pull-up resistor connected to V <sub>CC</sub> )	12	N. A.
AUX1	Auxiliary line to and from card (C4) (internal 11 k $\Omega$ pull-up resistor to V <sub>CC</sub> )	13	N. A.
CGND	Ground for card signal (C5)	14	9
CLK	Clock to card (C3)	15	10
RST	Card reset (C2)	16	11
V <sub>CC</sub>	Supply voltage for the card (C1)	17	12
PORADJ	Power-on reset threshold adjustment input (ST8024LCDR, ST8024LCTR)		N. A.
1.8V	1.8 V V <sub>CC</sub> operation selection. Logic high selects 1.8 V operation and overrides any setting on the 5V/3V pin. With an internal 11 k $\Omega$ pull-down resistor to GND. (ST8024LACDR, ST8024LACTR and ST8024LTR)	18	13
$\overline{\text{CMDVCC}}$	Start activation sequence input (active low)	19	14
RSTIN	Card reset input from MCU	20	15
V <sub>DD</sub>	Supply voltage	21	16
GND	Ground	22	17
$\overline{\text{OFF}}$	Interrupt to MCU (active low)	23	18
XTAL1	Crystal or external clock input	24	19
XTAL2	Crystal connection (leave this pin open if external clock is used)	25	N.A
I/OUC	MCU data I/O line (internal 11 k $\Omega$ pull-up resistor connected to V <sub>DD</sub> )	26	20
AUX1UC	Non-inverting receiver input (internal 11 k $\Omega$ pull-up resistor connected to V <sub>DD</sub> )	27	N. A.
AUX2UC	Non-inverting receiver input (internal 11 k $\Omega$ pull-up resistor connected to V <sub>DD</sub> )	28	N. A.



## 4 Maximum ratings

**Table 3. Absolute maximum ratings<sup>(1)</sup>**

Symbol	Parameter	Min.	Max.	Unit
$V_{DD}, V_{DDP}$	Supply voltage	-0.3	7	V
$V_{n1}$	Voltage on pins XTAL1, XTAL2, $5V/\sqrt{3V}$ , RSTIN, AUX2UC, AUX1UC, I/OUC, CLKDIV1, CLKDIV2, PORADJ/1.8V, CMDVCC, PRES, and $\overline{OFF}$	-0.3	$V_{DD} + 0.3$	V
$V_{n2}$	Voltage on card contact pins I/O, RST, AUX1, AUX2, and CLK	-0.3	$V_{CC} + 0.3$	V
$V_{n3}$	Voltage on pins $V_{UP}$ , C1+, and C1-		7	V
ESD1	MIL-STD-883 class 3 on card contact pins, $\overline{PRES}$ and PRES <sup>(2)</sup> , <sup>(3)</sup>	-6	6	kV
ESD2	MIL-STD-883 class 2 on $\mu$ C contact pins and RSTIN <sup>(2)</sup> , <sup>(3)</sup>	-2	2	kV
$T_{J(MAX)}$	Maximum operating junction temperature		150	°C
$T_{STG}$	Storage temperature range	-40	150	°C

1. Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.
2. All card contacts are protected against any short with any other card contact.
3. Method 3015 (HBM, 1500  $\Omega$ , 100 pF) 3 positive pulses and 3 negative pulses on each pin referenced to ground.

**Table 4. Thermal data**

Symbol	Parameter	Condition	SO-28	TSSOP-20 TSSOP-28	Unit
$R_{thJA}$	Thermal resistance junction-ambient temperature	Multilayer test board (JEDEC standard)	56	50	°C/W

**Table 5. Recommended operating conditions**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$T_A$	Temperature range		-25		85	°C

## 5 Electrical characteristics

**Table 6. Electrical characteristics over recommended operating condition**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
$V_{DD}$	Supply voltage		2.7		6.5	V
$V_{DDP}$	Supply voltage for the step-up converter	$V_{CC} = 5\text{ V}; I_{CC} < 80\text{ mA}$	4.0	5	6.5	V
		$V_{CC} = 3\text{ V}; I_{CC} < 65\text{ mA}$	4.0	5	6.5	
		$V_{CC} = 5\text{ V}; I_{CC} < 20\text{ mA}$	3.0		6.5	
		$V_{CC} = 3\text{ V}; I_{CC} < 20\text{ mA}$	2.7		6.5	
		$V_{CC} = 1.8\text{ V}; I_{CC} < 20\text{ mA}$	2.7		6.5	
$I_{DD}$	Supply current	Card inactive			1.2	mA
		Card active; $f_{CLK} = f_{XTAL}$ ; $C_L = 30\text{ pF}$			1.5	
$I_{DDP}$	Step-up converter supply current	Inactive mode			0.1	mA
		Active mode; $f_{CLK} = f_{XTAL}$ ; $C_L = 30\text{ pF}$ ; $I_{CC} = 0$			10	
		$V_{CC} = 5\text{ V}; I_{CC} = 80\text{ mA}$		50	200	
		$V_{CC} = 3\text{ V}; I_{CC} = 65\text{ mA}$		50	100	
		$V_{CC} = 1.8\text{ V}; I_{CC} = 45\text{ mA}$		30	60	
$V_{th2}$	Falling threshold voltage on $V_{DD}$	No external resistors at pin PORADJ; $V_{DD}$ level falling. See <a href="#">Figure 4</a> .	2.35	2.45	2.55	V
$V_{HYS2}$	Hysteresis of threshold voltage $V_{th2}$	No external resistors at pin PORADJ. See <a href="#">Figure 4</a> .	50	100	150	mV
$V_{th(ext)rise}$	External rising threshold voltage at pin PORADJ	External resistor divider at pin PORADJ; $V_{DD}$ level rising. See <a href="#">Section 6.2.2</a> .	1.17	1.20	1.23	V
$V_{th(ext)fall}$	External falling threshold voltage at pin PORADJ	External resistor divider at pin PORADJ; $V_{DD}$ level falling. See <a href="#">Section 6.2.2</a> .	1.11	1.14	1.17	V
$V_{HYS(ext)}$	Hysteresis of threshold voltage $V_{th(ext)}$	External resistor divider at pin PORADJ. See <a href="#">Section 6.2.2</a> .	30	60	90	mV
$\Delta V_{HYS(ext)}$	Hysteresis of threshold voltage $V_{th(ext)}$ variation with temperature	External resistor divider at pin PORADJ			0.25	mV/K
$t_W$	Width of internal power-on reset pulse	No external resistor divider at pin PORADJ	4	8	12	ms
		External resistor divider at pin PORADJ	8	16	24	
$I_L$	Leakage current on pin PORADJ	$V_{PORADJ} < 0.5\text{ V}$	-0.1	4	10	$\mu\text{A}$
		$V_{PORADJ} > 1.0\text{ V}$	-1		1	
$P_{TOT}$	Total power dissipation	Continuous operation; $T_A = -25\text{ to }85\text{ }^\circ\text{C}$			0.56	W

1.  $V_{DD} = 3.3\text{ V}$ ,  $V_{DDP} = 5\text{ V}$ ,  $f_{XTAL} = 10\text{ MHz}$ , unless otherwise noted. Typical values are at  $T_A = 25\text{ }^\circ\text{C}$ .

Table 7. Step-up converter

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
$f_{CLK}$	Clock frequency	Card active	2.2		3.2	MHz
$V_{th(vd-vf)}$	Threshold voltage for step-up converter to change to voltage follower	5 V card	5.2	5.8	6.2	V
		3 V card	3.8	4.1	4.4	
		1.8 V card	3.8	4.1	4.4	
$V_{UP}$	Output voltage on pin $V_{UP}$ (average value)	5 V card	5.2	5.7	6.2	V
		3 V card	3.5	3.9	4.3	
		1.8 V card	3.5	3.9	4.3	

1.  $V_{DD} = 3.3$  V,  $V_{DDP} = 5$  V,  $f_{XTAL} = 10$  MHz, unless otherwise noted. Typical values are at  $T_A = 25$  °C.

Table 8. Card supply voltage characteristics

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit	
$C_{VCC}$	External capacitance on pin $V_{CC}$	See <sup>(2)</sup>	80		400	nF	
$V_{CC}$	Card supply voltage (including ripple voltage)	Card inactive; $ I_{CC}  = 0$ mA	5 V, 3 V and 1.8 V card	-0.1	0	0.1	V
		Card inactive; $ I_{CC}  = 1$ mA	5 V, 3 V and 1.8 V card	-0.1	0	0.3	
		Card active; $ I_{CC}  < 80$ mA	5 V card	4.75	5	5.25	
		Card active; $ I_{CC}  < 65$ mA	3 V card	2.85	3	3.15	
		Card active; $ I_{CC}  < 45$ mA	1.8 V card	1.68	1.8	1.92	
		Card active; single current pulse $I_P = -100$ mA; $t_p = 2$ $\mu$ s	5 V card	4.65	5	5.25	
		Card active; single current pulse $I_P = -100$ mA; $t_p = 2$ $\mu$ s	3 V card	2.76	3	3.20	
		Card active; single current pulse $I_P = -100$ mA; $t_p = 2$ $\mu$ s	1.8 V card	1.62	1.8	1.98	
		Card active; current pulses, $Q_P = 40$ nAs	5 V card	4.65	5	5.25	
			3 V card	2.76	3	3.20	
			1.8 V card	1.62	1.8	1.98	
		Card active; current pulses $Q_P = 40$ nAs with $ I_{CC}  < 200$ mA, $t_p < 400$ ns	5 V card	4.65	5	5.25	
			3 V card	2.76	3	3.20	
1.8 V card	1.62		1.8	1.98			
$V_{CC}$ (RIPPLE) (P-P)	Ripple voltage on $V_{CC}$ (peak-to-peak value)	$f_{RIPPLE} = 20$ kHz to 200 MHz			350	mV	

**Table 8. Card supply voltage characteristics (continued)**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
I <sub>CC</sub>	Card supply current	V <sub>CC</sub> = 0 to 5 V			80	mA
		V <sub>CC</sub> = 0 to 3 V			65	
		V <sub>CC</sub> = 0 to 1.8 V			45	
		V <sub>CC</sub> short-circuit to GND	90		120	
S <sub>R</sub>	Slew rate	Slew up or down, V <sub>CC</sub> = 5 V; 3 V; 1.8 V; I <sub>CC</sub> < 30 mA	0.08	0.15	0.22	V/μs

- V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>XTAL</sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C. (All parameters remain within limits but are tested only statistically for the temperature range. When a parameter is specified as a function of V<sub>DD</sub> or V<sub>CC</sub> it means their actual value at the moment of measurement.)
- To meet these specifications, pin VCC should be decoupled to CGND using two 100 nF ceramic multilayer capacitors of max. 350 mΩ ESR. If V<sub>CC</sub> slew rate is not critical, the capacitance value can be up to 400 nF. (See [Figure 10](#)).

**Table 9. Crystal connection (pins XTAL1 and XTAL2)**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
C <sub>XTAL1,2</sub>	External capacitance on pins XTAL1, XTAL2	Depends on type of crystal or resonator used		-	15	pF
f <sub>XTAL</sub>	Crystal frequency		2	-	26	MHz
f <sub>XTAL1</sub>	Frequency applied on pin XTAL1		0	-	26	MHz
V <sub>IH</sub>	High level input voltage on pin XTAL1		0.7 V <sub>DD</sub>	-	V <sub>DD</sub> +0.3	V
V <sub>IL</sub>	Low level input voltage on pin XTAL1		-0.3	-	+0.3 V <sub>DD</sub>	V

- V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>XTAL</sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

**Table 10. Data lines (pins I/O, I/OUC, AUX1, AUX2, AUX1UC, and AUX2UC)**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
t <sub>D(I/O-I/OUC), t<sub>D(I/OUC-I/O)</sub></sub>	I/O to I/OUC, I/OUC to I/O falling edge delay		-	-	200	ns
t <sub>PU</sub>	Active pull-up pulse width		-	-	100	ns
f <sub>I/O(MAX)</sub>	Maximum frequency on data lines		-	-	1	MHz
C <sub>I</sub>	Input capacitance on data lines		-	-	10	pF

- V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>XTAL</sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

**Table 11. Data lines to card reader (pins I/O, AUX1, and AUX2 with integrated 11 kΩ pull-up resistor to V<sub>CC</sub>)**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit	
V <sub>O(inactive)</sub>	Output voltage	Inactive mode	No load	0		0.1	V
			I <sub>O(inactive)</sub> = 1 mA			0.3	
I <sub>O(inactive)</sub>	Output current	Inactive mode; pin grounded			-1	mA	
V <sub>OH</sub>	High level output voltage	No DC load	0.9 V <sub>CC</sub>		V <sub>CC</sub> +0.1	V	
		5 V and 3 V cards; I <sub>OH</sub> < -40 μA	0.75 V <sub>CC</sub>		V <sub>CC</sub> +0.1		
		1.8 V card I <sub>OH</sub> < -40 μA	0.75 V <sub>CC</sub>				
		I <sub>OH</sub>   ≥ 10 mA	0		0.4		
V <sub>OL</sub>	Low level output voltage	I <sub>OL</sub> = 1 mA	0		0.2	V	
		I <sub>OL</sub> ≥ 15 mA	V <sub>CC</sub> -0.4		V <sub>CC</sub>		
V <sub>IH</sub>	High level input voltage	5 V and 3 V cards	1.5		V <sub>CC</sub> +0.3	V	
		1.8 V card	0.6 V <sub>CC</sub>				
V <sub>IL</sub>	Low level input voltage	5 V and 3 V cards	0.3		1.0	V	
		1.8 V card	0		0.2		
I <sub>L IH</sub>	High level input leakage current	V <sub>IH</sub> = V <sub>CC</sub>			10	μA	
I <sub>L L</sub>	Low level input current	V <sub>IL</sub> = 0 V			600	μA	
R <sub>PU</sub>	Integrated pull-up resistor	Pull-up resistor to V <sub>CC</sub>	9	11	13	kΩ	
t <sub>T(DI)</sub>	Data input transition time	V <sub>IL</sub> max. to V <sub>IH</sub> min.			1.2	μs	
t <sub>T(DO)</sub>	Data output transition time	V <sub>O</sub> = 0 to V <sub>CC</sub> ; C <sub>L</sub> ≤ 80 pF; 10% to 90%			0.1	μs	
I <sub>PU</sub>	Current when pull-up active	V <sub>OH</sub> = 0.9 V <sub>CC</sub> ; C <sub>L</sub> = 80 pF	-2			mA	

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>X TAL</sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

**Table 12. Data lines to microcontroller (pins I/OUC, AUX1UC, and AUX2UC with integrated 11 kΩ pull-up resistor to V<sub>DD</sub>)**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
V <sub>OH</sub>	High level output voltage	5 V, 3 V and 1.8 V cards; I <sub>OH</sub> < -40 μA	0.75 V <sub>DD</sub>		V <sub>DD</sub> +0.1	V
		No DC load	0.9 V <sub>DD</sub>		V <sub>DD</sub> +0.1	
V <sub>OL</sub>	Low level output voltage	I <sub>OL</sub> = 1 mA	0		0.3	V
V <sub>IH</sub>	High level input voltage		0.7 V <sub>DD</sub>		V <sub>DD</sub> +0.3	V
V <sub>IL</sub>	Low level input voltage		-0.3		0.3 V <sub>DD</sub>	V
I <sub>LH</sub>	High level input leakage current	V <sub>IH</sub> = V <sub>DD</sub>			10	μA
I <sub>L</sub>	Low level input current	V <sub>IL</sub> = 0 V			600	μA
R <sub>PU</sub>	Internal pull-up resistance to V <sub>DD</sub>	Pull-up resistor to V <sub>DD</sub>	9	11	13	kΩ
t <sub>T(DI)</sub>	Data input transition time	V <sub>IL</sub> max. to V <sub>IH</sub> min.			1.2	μs
t <sub>T(DO)</sub>	Data output transition time	V <sub>O</sub> = 0 to V <sub>DD</sub> ; C <sub>L</sub> < 30 pF; 10% to 90%			0.1	μs
I <sub>PU</sub>	Current when pull-up active	V <sub>OH</sub> = 0.9 V <sub>DD</sub> ; C <sub>L</sub> = 30 pF	-1			mA

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>X<sub>TAL</sub></sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

**Table 13. Internal oscillator**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
f <sub>OSC(INT)</sub>	Frequency of internal oscillator	Inactive mode	55	140	200	kHz
		Active mode	2.2	2.7	3.2	MHz

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>X<sub>TAL</sub></sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

**Table 14. Reset output to card reader (pin RST)**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
V <sub>O(inactive)</sub>	Output voltage in inactive mode	I <sub>O(inactive)</sub> = 1 mA	0	-	0.3	V
		No load	0	-	0.1	
I <sub>O(inactive)</sub>	Output current	Inactive mode; pin grounded	0	-	-1	mA
t <sub>D(RSTIN-RST)</sub>	RSTIN to RST delay	RST enable		-	2	μs
V <sub>OL</sub>	Low level output voltage	I <sub>OL</sub> = 200 μA	0	-	0.2	V
		I <sub>OL</sub> = 20 mA (current limit)	V <sub>CC</sub> -0.4	-	V <sub>CC</sub>	
V <sub>OH</sub>	High level output voltage	I <sub>OH</sub> = -200 μA	0.9 V <sub>CC</sub>	-	V <sub>CC</sub>	V
		I <sub>OH</sub> = -20 mA (current limit)	0	-	0.4	
t <sub>R</sub> , t <sub>F</sub>	Rise and fall time	C <sub>L</sub> = 100 pF		-	0.1	μs

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>X<sub>TAL</sub></sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

Table 15. Clock output to card reader (pin CLK)

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
V <sub>O(inactive)</sub>	Output voltage in inactive mode	I <sub>O(inactive)</sub> = 1 mA	0	-	0.3	V
		No load	0	-	0.1	
I <sub>O(inactive)</sub>	Output current	CLK inactive mode; pin grounded	0	-	-1	mA
V <sub>OL</sub>	Low level output voltage	I <sub>OL</sub> = 200 μA	0	-	0.3	V
		I <sub>OL</sub> = 70 mA (current limit)	V <sub>CC</sub> - 0.4	-	V <sub>CC</sub>	
V <sub>OH</sub>	High level output voltage	I <sub>OH</sub> = -200 μA	0.9 V <sub>CC</sub>	-	V <sub>CC</sub>	V
		I <sub>OH</sub> = -70 mA (current limit)	0	-	0.4	
t <sub>R</sub> , t <sub>F</sub>	Rise and fall time	C <sub>L</sub> = 30 pF <sup>(2)</sup>		-	16	ns
δ	Duty factor (except for f <sub>X<sub>TAL</sub></sub> )	C <sub>L</sub> = 30 pF <sup>(2)</sup>	45	-	55	%
S <sub>R</sub>	Slew rate	Slew up or down; C <sub>L</sub> = 30 pF	0.2	-		V/ns

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>X<sub>TAL</sub></sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

2. Transition time and duty factor definitions are shown in [Figure 3](#); d = t<sub>1</sub>/(t<sub>1</sub> + t<sub>2</sub>).

Table 16. Control inputs (pins CLKDIV1, CLKDIV2,  $\overline{\text{CMDVCC}}$ , RSTIN, 5V/3V and PORADJ/1.8V)

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
V <sub>IL</sub>	Low level input voltage		-0.3		0.3 V <sub>DD</sub>	V
V <sub>IH</sub>	High level input voltage		0.7 V <sub>DD</sub>		V <sub>DD</sub>	V
I <sub>LIH</sub>	High level input leakage current	V <sub>IH</sub> = V <sub>DD</sub>			1	μA
		V <sub>IH</sub> = V <sub>DD</sub> , 1.8V and CLKDIV2 pins with internal 11 kΩ pull-down resistor			800	μA
I <sub>LIL</sub>	Low level input leakage current	V <sub>IL</sub> = 0	-1			μA
		V <sub>IL</sub> = 0, CLKDIV1 pin with internal 11 kΩ pull-up resistor	-800			μA
R <sub>PD</sub>	Internal pull-down resistor to GND	Pull-down resistor to GND (1.8V and CLKDIV2 pins)	9	11	13	kΩ
R <sub>PU</sub>	Internal pull-up resistor to V <sub>DD</sub>	Pull-up resistor to V <sub>DD</sub> (CLKDIV1 pin)	9	11	13	kΩ

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>X<sub>TAL</sub></sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C. Pin CMDVCC is active low; pin RSTIN is active high; for CLKDIV1 and CLKDIV2 functions (see [Table 21](#)).

**Table 17. Card presence inputs (pins PRES and  $\overline{\text{PRES}}$ )**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
V <sub>IL</sub>	Low level input voltage		-0.3	-	0.3 V <sub>DD</sub>	V
V <sub>IH</sub>	High level input voltage		0.7 V <sub>DD</sub>	-	V <sub>DD</sub> + 0.3	V
I <sub>LIH</sub>	High level input leakage current	V <sub>IH</sub> = V <sub>DD</sub>		-	5	μA
I <sub>LIL</sub>	Low level input leakage current	V <sub>IL</sub> = 0		-	5	μA

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>XTAL</sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C  
Pin PRES is active low; pin  $\overline{\text{PRES}}$  is active high, see [Figure 8](#) and [Figure 9](#); PRES has an integrated 1.25 μA current source to GND. ( $\overline{\text{PRES}}$  to V<sub>DD</sub>); the card is considered present if at least one of the inputs PRES or  $\overline{\text{PRES}}$  is active.

**Table 18. Interrupt output (pin  $\overline{\text{OFF}}$  NMOS drain with integrated 20 kΩ pull-up resistor to V<sub>DD</sub>)**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
V <sub>OL</sub>	Low level output voltage	I <sub>OL</sub> = 2 mA	0		0.3	V
V <sub>OH</sub>	High level output voltage	I <sub>OH</sub> = -15 μA	0.75 V <sub>DD</sub>			V
R <sub>PU</sub>	Integrated pull-up resistor	20 kΩ pull-up resistor to V <sub>DD</sub>	16	20	24	kΩ

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>XTAL</sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

**Table 19. Protection and limitation**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
I <sub>CC(SD)</sub>	Shutdown and limitation current pin V <sub>CC</sub>		90		120	mA
I <sub>I/O(lim)</sub>	Limitation current pins I/O, AUX1 and AUX2		-15		15	mA
I <sub>CLK(lim)</sub>	Limitation current pin CLK		-70		70	mA
I <sub>RST(lim)</sub>	Limitation current pin RST		-20		20	mA
T <sub>SD</sub>	Shutdown temperature			150		°C

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>XTAL</sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.

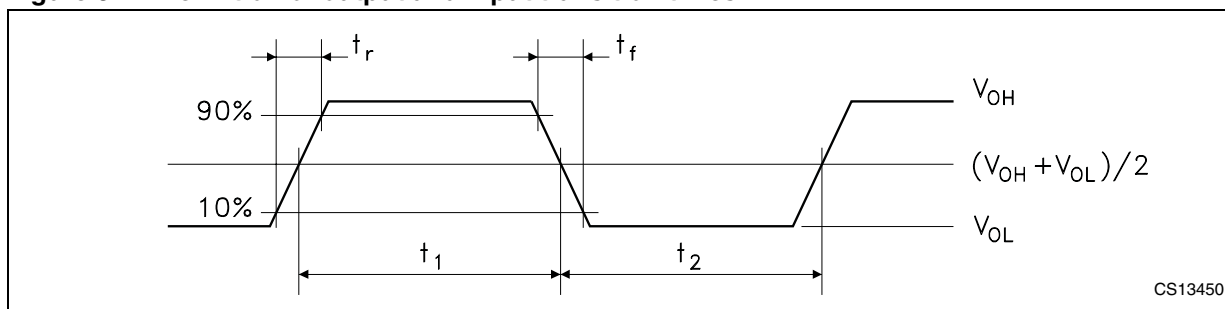
**Table 20. Timing**

Symbol	Parameter <sup>(1)</sup>	Test conditions	Min.	Typ.	Max.	Unit
t <sub>ACT</sub>	Activation time	For V <sub>CC</sub> = 5 V (See <a href="#">Figure 5</a> )	50		220	μs
t <sub>DE</sub>	Deactivation time	(See <a href="#">Figure 7</a> )	50	80	100	μs
t <sub>3</sub>	Start of the window for sending CLK to card	(See <a href="#">Figure 6</a> )			130	μs
t <sub>5</sub>	End of the window for sending CLK to card	(See <a href="#">Figure 6</a> )	140			μs
t <sub>debounce</sub>	Debounce time pins PRES and $\overline{\text{PRES}}$	(See <a href="#">Figure 8</a> )	5	8	11	ms

1. V<sub>DD</sub> = 3.3 V, V<sub>DDP</sub> = 5 V, f<sub>XTAL</sub> = 10 MHz, unless otherwise noted. Typical values are at T<sub>A</sub> = 25 °C.



Figure 3. Definition of output and input transition times



## 6 Functional description

Throughout this document it is assumed that the reader is familiar with ISO7816 terminology.

### 6.1 Power supply

The supply pins for the ST8024L are  $V_{DD}$  and GND.  $V_{DD}$  should be in the range of 2.7 to 6.5 V. All signals interfacing with the system controller are referred to  $V_{DD}$ , therefore  $V_{DD}$  should also supply the system controller. All card reader contacts remain inactive during power-on or power-off.

The internal circuits are kept in the reset state until  $V_{DD}$  reaches  $V_{th2} + V_{HYS2}$  and for the duration of the internal power-on reset pulse,  $t_W$  (see [Figure 4](#)). When  $V_{DD}$  falls below  $V_{th2}$ , an automatic deactivation of the contacts is performed.

A step-up converter is incorporated to generate the 1.8 V (for those devices with the 1.8V pin), 3 V, or 5 V card supply voltage ( $V_{CC}$ ). The step-up converter should be supplied separately by  $V_{DDP}$  and PGND. Due to the possibility of large transient currents, the two 100 nF capacitors of the step-up converter should be located as near as possible to the ST8024L and have an ESR less than 350 m $\Omega$ .

During power-up, the  $V_{DD}$  supply voltage must be applied prior to the  $V_{DDP}$  supply voltage or at the same time

After powering the device,  $\overline{OFF}$  remains low until  $\overline{CMDVCC}$  is set high.

During power-off,  $\overline{OFF}$  falls low when  $V_{DD}$  is below the falling threshold voltage.

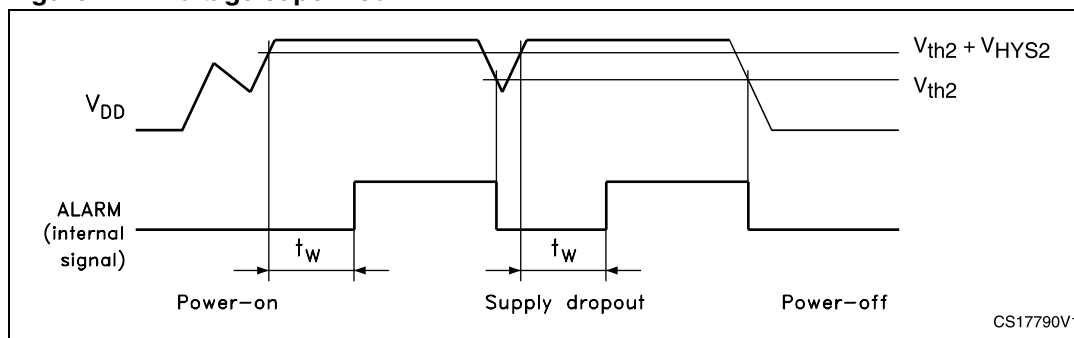
### 6.2 Voltage supervisor

#### 6.2.1 Without external divider on pin PORADJ

The voltage supervisor surveys the  $V_{DD}$  supply. A defined reset pulse of approximately 8 ms ( $t_W$ ) is used internally to keep the ST8024L inactive during power-on or power-off of the  $V_{DD}$  supply (see [Figure 4](#)).

As long as  $V_{DD}$  is less than  $V_{th2} + V_{HYS2}$ , the ST8024L remains inactive regardless of the levels on the command lines. This state also lasts for the duration of  $t_W$  after  $V_{DD}$  has reached a level higher than  $V_{th2} + V_{HYS2}$ . When  $V_{DD}$  falls below  $V_{th2}$ , a deactivation sequence of the contacts is performed.

**Figure 4. Voltage supervisor**



### 6.2.2 With an external divider on pin PORADJ

In this case, a resistor divider is connected to the PORADJ pin (see [Figure 1](#)).  $V_{th(ext) rise}$  and  $V_{th(ext) fall}$  are the external rising threshold voltage and the external falling threshold voltages on pin PORADJ that switch the device on and off. By knowing these values and using the formula:

$$V_{DD} \text{ UVLO threshold (falling)} = (R_1 + R_2) / R_2 \times V_{th(ext)fall}$$

$$V_{DD} \text{ UVLO threshold (rising)} = (R_1 + R_2) / R_2 \times V_{th(ext)rise}$$

it is possible to set  $R_1$  and  $R_2$  in order to get suitable values for  $V_{DD}$  undervoltage (UVLO) thresholds, in order to turn the device on and off ( $R_1 + R_2 = 100 \text{ k}\Omega$  typ.).

In particular,  $R_1$  and  $R_2$  must be set so that, when  $V_{DD}$  is getting low, before turning the microcontroller off, the smartcard must also be switched off properly. The same is true for the microcontroller startup - in such case the smartcard must be turned on after the microcontroller. The reset pulse width  $t_w$  is doubled to approximately 16 ms.

Input PORADJ is biased internally with a pull-down current source of 4  $\mu\text{A}$  which is removed when the voltage on pin PORADJ exceeds 1 V.

This ensures that after detection of the external divider by the ST8024L during power-on, the input current on pin PORADJ does not cause inaccuracy of the divider voltage.

*Note: The  $V_{th(ext)}$  threshold of the ST8024L is slightly lower (by 80 mV typ.) than it was in the case of the ST8024 device. If, for example, the microcontroller is shut down at 2.5 V, the appropriate external resistor values must be chosen to ensure proper deactivation of the ST8024L device.*

### 6.2.3 Application examples

The voltage supervisor is used as power-on reset and as supply dropout detection during a card session. Supply dropout detection is to ensure that a proper deactivation sequence is followed before the voltage is too low. For the internal voltage supervisor to function, the system microcontroller should operate down to 2.35 V to ensure a proper deactivation sequence. If this is not possible, external resistor values can be chosen to overcome the problem.

### 6.3 Clock circuitry (only on SO-28 and TSSOP-28 packages)

The card clock signal (CLK) is derived from a clock signal input to pin XTAL1 or from a crystal operating at up to 26 MHz connected between pins XTAL1 and XTAL2.

The clock frequency can be  $f_{XTAL}$ ,  $1/2 \times f_{XTAL}$ ,  $1/4 \times f_{XTAL}$ , or  $1/8 \times f_{XTAL}$ . Frequency selection is made via inputs CLKDIV1 and CLKDIV2 (see [Table 21](#)).

**Table 21. Clock frequency selection<sup>(1)</sup>**

CLKDIV1	CLKDIV2	$f_{CLK}$
0	0	$f_{XTAL}/8$
0	1	$f_{XTAL}/4$
1	1	$f_{XTAL}/2$
1	0	$f_{XTAL}$

1. The status of pins CLKDIV1 and CLKDIV2 must not be changed simultaneously; a delay of 10 ns minimum between changes is needed. The minimum duration of any state of CLK is eight periods of XTAL1.

The frequency change is synchronous, which means that during transition no pulse is shorter than 45% of the smallest period, and that the first and last clock pulses regarding the instant of change have the correct width.

When changing the frequency dynamically, the change is effective for only eight periods of XTAL1 after the command. The duty factor of  $f_{XTAL}$  depends on the signal present at pin XTAL1. In order to reach a 45 to 55% duty factor on pin CLK, the input signal on pin XTAL1 should have a duty factor of 48 to 52% and transition times of less than 5% of the input signal period.

If a crystal is used, the duty factor on pin CLK may be 45 to 55% depending on the circuit layout and on the crystal characteristics and frequency. In other cases, the duty factor on pin CLK is guaranteed between 45 and 55% of the clock period.

The crystal oscillator runs as soon as the ST8024L is powered up. If the crystal oscillator is used, or if the clock pulse on pin XTAL1 is permanent, the clock pulse is applied to the card as shown in the activation sequences in [Figure 5](#) and [Figure 6](#).

If the signal applied to XTAL1 is controlled by the system microcontroller, the clock pulse is applied to the card when it is sent by the system microcontroller (after completion of the activation sequence).

## 6.4 I/O transceivers

The three data lines I/O, AUX1, and AUX2 are identical. The idle state is realized by both I/O and I/OUC lines being pulled high via an 11 k $\Omega$  resistor (I/O to  $V_{CC}$  and I/OUC to  $V_{DD}$ ). Pin I/O is referenced to  $V_{CC}$ , and pin I/OUC to  $V_{DD}$ , therefore allowing operation when  $V_{CC}$  is not equal to  $V_{DD}$ . The first side of the transceiver to receive a falling edge becomes the master. An anti-latch circuit disables the detection of falling edges on the line of the other side, which then becomes a slave. After a time delay  $t_{d(\text{edge})}$ , an N transistor on the slave side is turned on, therefore transmitting the logic 0 present on the master side. When the master side returns to logic 1, a P transistor on the slave side is turned on during the time delay  $t_{PU}$  and then both sides return to their idle states. This active pull-up feature ensures fast low to high transitions; it is able to deliver more than 1 mA, at an output voltage of up to 0.9  $V_{CC}$ , into an 80 pF load. At the end of the active pull-up pulse, the output voltage depends only on the internal pull-up resistor and the load current. The current to and from the card I/O lines is limited internally to 15 mA and the maximum frequency on these lines is 1 MHz.

## 6.5 Inactive mode

After a power-on reset, the circuit enters inactive mode. A minimum number of circuits are active while waiting for the microcontroller to start a session:

- All card contacts are inactive (approximately 200  $\Omega$  to GND)
- Pins I/OUC, AUX1UC, and AUX2UC are in the high impedance state (11 k $\Omega$  pull-up resistor to  $V_{DD}$ ). Applies only to SO-28 and TSSOP-28 packages.
- Voltage generators are stopped
- XTAL oscillator is running
- Voltage supervisor is active
- The internal oscillator is running at its low frequency.

## 6.6 Activation sequence

After power-on and after the internal pulse width delay, the system microcontroller can check the presence of a card using the signals  $\overline{\text{OFF}}$  and  $\overline{\text{CMDVCC}}$ , as shown in [Table 22](#).

If the card is in the reader (this is the case if  $\overline{\text{PRES}}$  or PRES is active), the system microcontroller can start a card session by pulling  $\overline{\text{CMDVCC}}$  low. The following sequence then occurs (see [Figure 6](#)):

1.  $\overline{\text{CMDVCC}}$  is pulled low and the internal oscillator changes to its high frequency ( $t_0$ ).
2. The step-up converter is started (between  $t_0$  and  $t_1$ ).
3.  $V_{CC}$  rises from 0 to 5 V (or 1.8 V, 3 V) with a controlled slope ( $t_2 = t_1 + 1.5 \times T$ ) where T is 64 times the period of the internal oscillator (approximately 25  $\mu\text{s}$ ).
4. I/O, AUX1, and AUX2 are enabled ( $t_3 = t_1 + 4T$ ) (these were pulled low until this moment).
5. CLK is applied to the C3 contact of the card reader ( $t_4$ ).
6. RST is enabled ( $t_5 = t_1 + 7T$ ).

The clock may be applied to the card using the following sequence (see *Figure 5*):

1. Set RSTIN high.
2. Set  $\overline{\text{CMDVCC}}$  low.
3. Reset RSTIN low between  $t_3$  and  $t_5$ ; CLK starts at this moment.
4. RST remains low until  $t_5$ , when RST is enabled to be the copy of RSTIN.
5. After  $t_5$ , RSTIN has no further affect on CLK; this allows a precise count of CLK pulses before toggling RST.

If the applied clock is not needed, then  $\overline{\text{CMDVCC}}$  may be set low with RSTIN low. In this case, CLK starts at  $t_3$  (minimum 200 ns after the transition on I/O), and after  $t_5$ , RSTIN may be set high in order to obtain an “answer to request” (ATR) from the card.

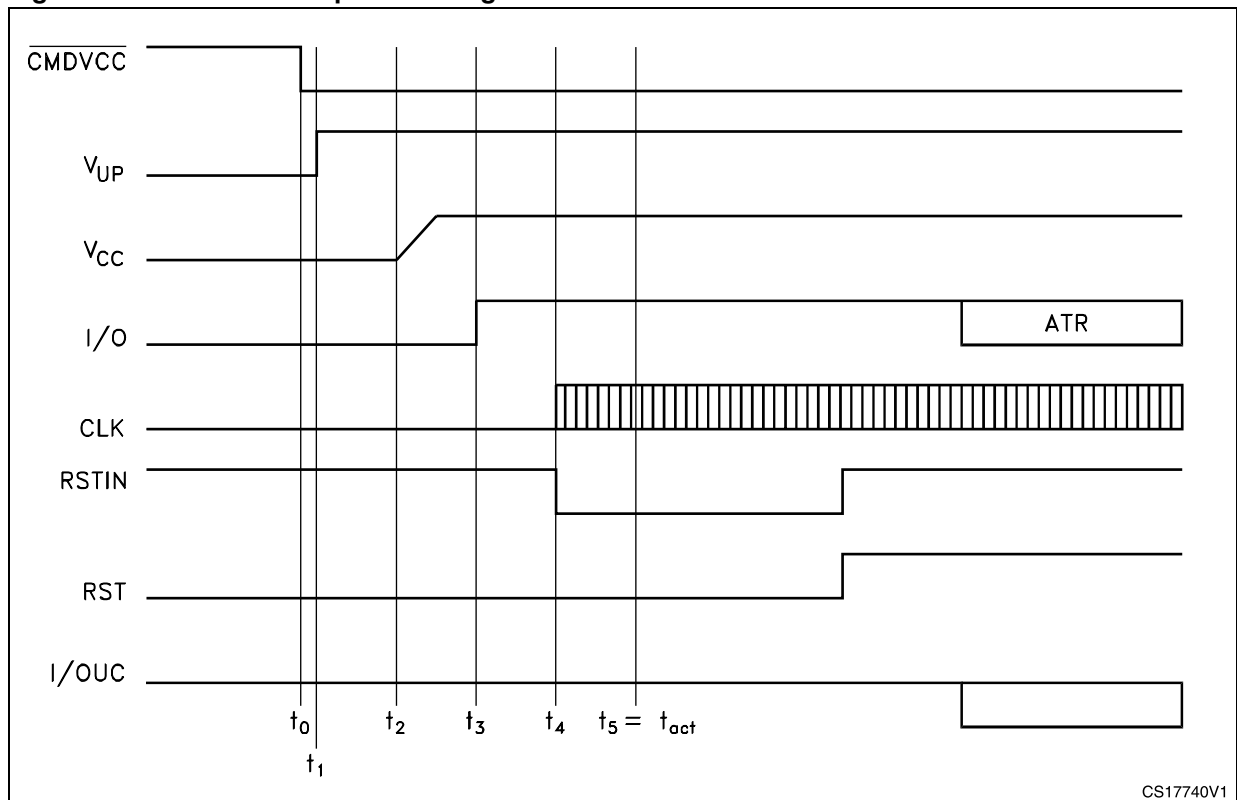
Activation should not be performed with RSTIN held permanently high.

*Note: It is recommended that no control smartcard signals are to be shared with any other devices. Sharing may result in inadvertent activation or deactivation of the smartcard.*

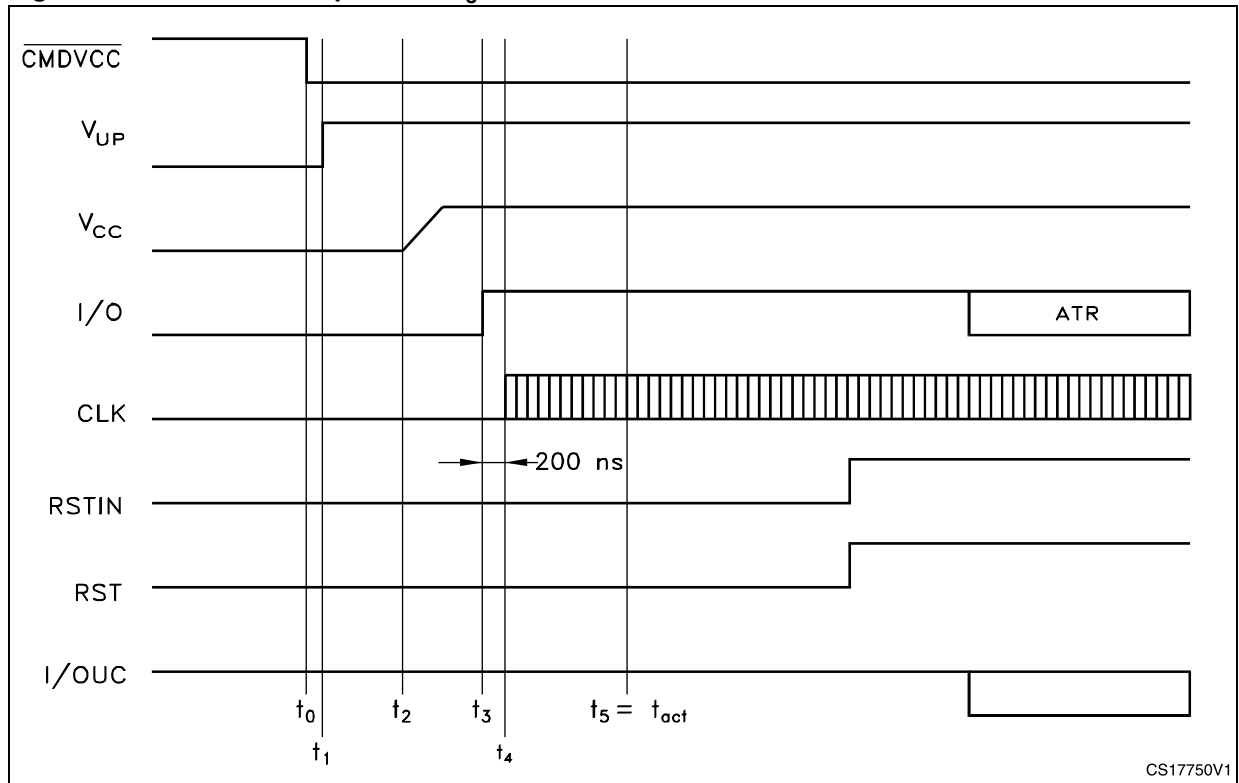
**Table 22. Card presence indicator**

$\overline{\text{OFF}}$	$\overline{\text{CMDVCC}}$	Indication
H	H	Card present
L	H	Card not present

**Figure 5. Activation sequence using RSTIN and  $\overline{\text{CMDVCC}}$**



CS17740V1

Figure 6. Activation sequence at  $t_3$ 

## 6.7 Active mode

When the activation sequence is completed, the ST8024L is in its active mode. Data are exchanged between the card and the microcontroller via the I/O lines.

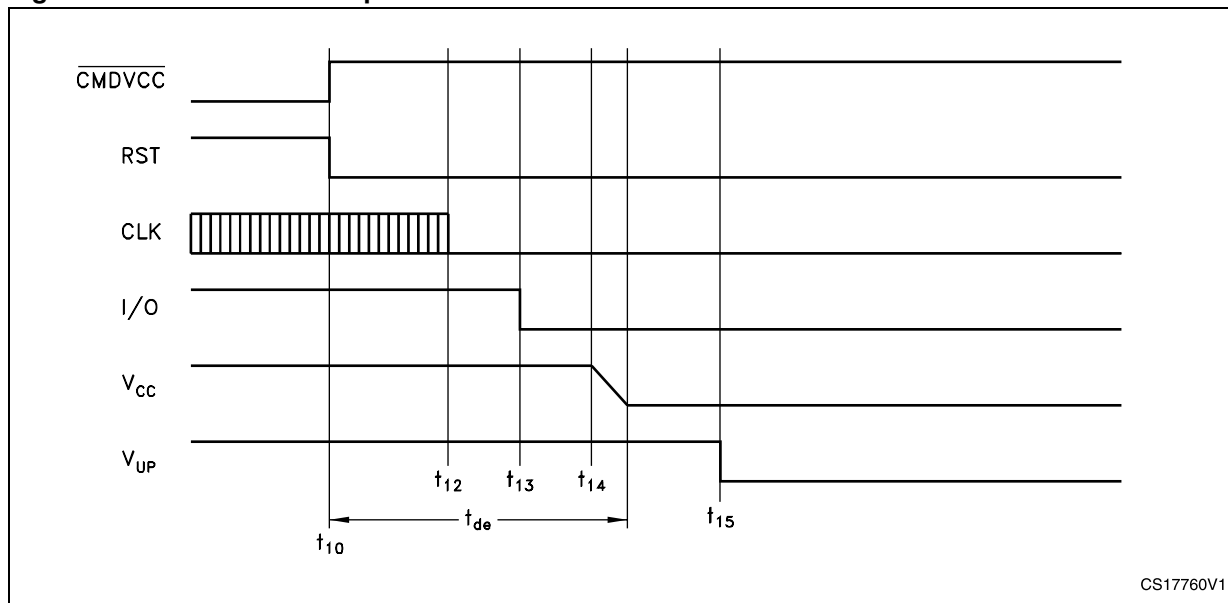
The ST8024L is designed for cards without  $V_{PP}$  (the voltage required to program or erase the internal non-volatile memory).

## 6.8 Deactivation sequence

When a session is completed, the microcontroller sets the  $\overline{\text{CMDVCC}}$  line HIGH. The circuit then executes an automatic deactivation sequence by counting the sequencer back and finishing in the inactive mode (see [Figure 7](#)):

1. RST goes low ( $t_{10}$ ).
2. CLK is held low ( $t_{12} = t_{10} + 0.5 \times T$ ) where T is 64 times the period of the internal oscillator (approximately 25  $\mu\text{s}$ ).
3. I/O, AUX1, and AUX2 are pulled low ( $t_{13} = t_{10} + T$ ).
4.  $V_{CC}$  starts to fall towards zero ( $t_{14} = t_{10} + 1.5 \times T$ ).
5. The deactivation sequence is complete at  $t_{DE}$ , when  $V_{CC}$  reaches its inactive state.
6. All card contacts become low impedance to GND; I/OUC, AUX1UC, and AUX2UC remain at  $V_{DD}$  (pulled-up via an 11 k $\Omega$  resistor).
7. The internal oscillator returns to its lower frequency.

Figure 7. Deactivation sequence



### 6.9 V<sub>CC</sub> generator

The V<sub>CC</sub> generator has a capacity to supply up to 80 mA (max.) continuously at 5 V, 65 mA (max.) at 3 V, and 45 mA (max.) at 1.8 V. An internal overload detector operates at approximately 120 mA. Current samples to the detector are internally filtered, allowing spurious current pulses up to 200 mA with a duration in the order of  $\mu$ s to be drawn by the card without causing deactivation. The average current must stay below the specified maximum current value. For reasons of V<sub>CC</sub> voltage accuracy, a 100 nF capacitor with an ESR < 350 m $\Omega$  should be tied to CGND near to pin V<sub>CC</sub>, and a 100 nF capacitor with the same ESR should be tied to CGND near card reader contact C1.



## 6.10 Fault detection

The following fault conditions are monitored:

- Short-circuit or high current on  $V_{CC}$
- Removal of a card during a transaction
- $V_{DD}$  dropping
- Step-up converter operating out of the specified values ( $V_{DDP}$  too low or current from  $V_{UP}$  too high)
- Overheating
- There are two different cases (see [Figure 8](#)):
  - $\overline{CMDVCC}$  high outside a card session. Output  $\overline{OFF}$  is low if a card is not in the card reader, and high if a card is in the reader. A voltage drop on the  $V_{DD}$  supply is detected by the supply supervisor, this generates an internal power-on reset pulse but does not act upon  $\overline{OFF}$ . No short-circuit or overheating is detected because the card is not powered-up.
  - $\overline{CMDVCC}$  low within a card session. Output  $\overline{OFF}$  goes low when a fault condition is detected. As soon as this occurs, an emergency deactivation is performed automatically (see [Figure 9](#)). When the system controller resets  $\overline{CMDVCC}$  to high, it may sense the  $\overline{OFF}$  level again after completing the deactivation sequence. This distinguishes between a hardware problem or a card extraction ( $\overline{OFF}$  goes high again if a card is present).

Depending on the type of card-present switch within the connector (normally closed or normally open) and on the mechanical characteristics of the switch, bouncing may occur on the PRES signals at card insertion or withdrawal.

There is a debounce feature in the device with an 8 ms typical duration (see [Figure 8](#)). When a card is inserted, output  $\overline{OFF}$  goes high only at the end of the debounce time.

When the card is extracted, an automatic deactivation sequence of the card is performed on the first true/false transition on PRES or  $\overline{PRES}$  and output  $\overline{OFF}$  goes low.

**Figure 8. Behavior of  $\overline{OFF}$ ,  $\overline{CMDVCC}$ , PRES, and  $V_{CC}$**

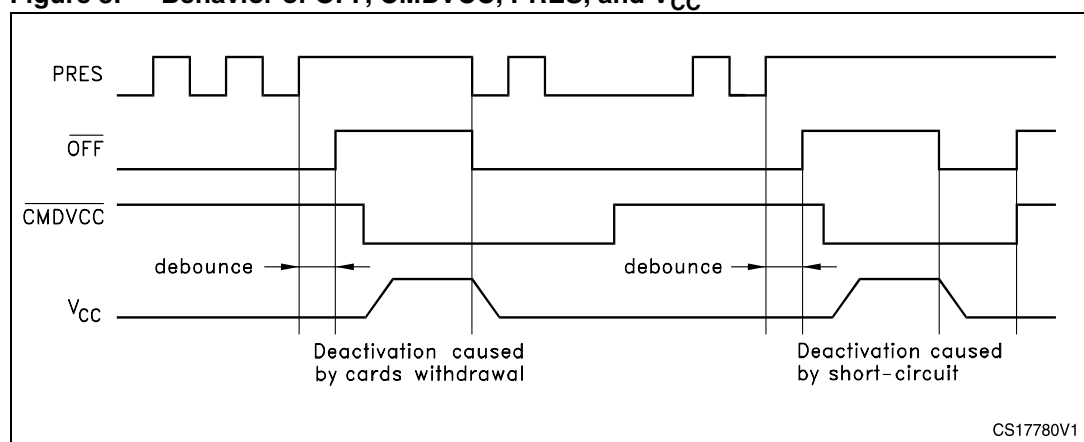
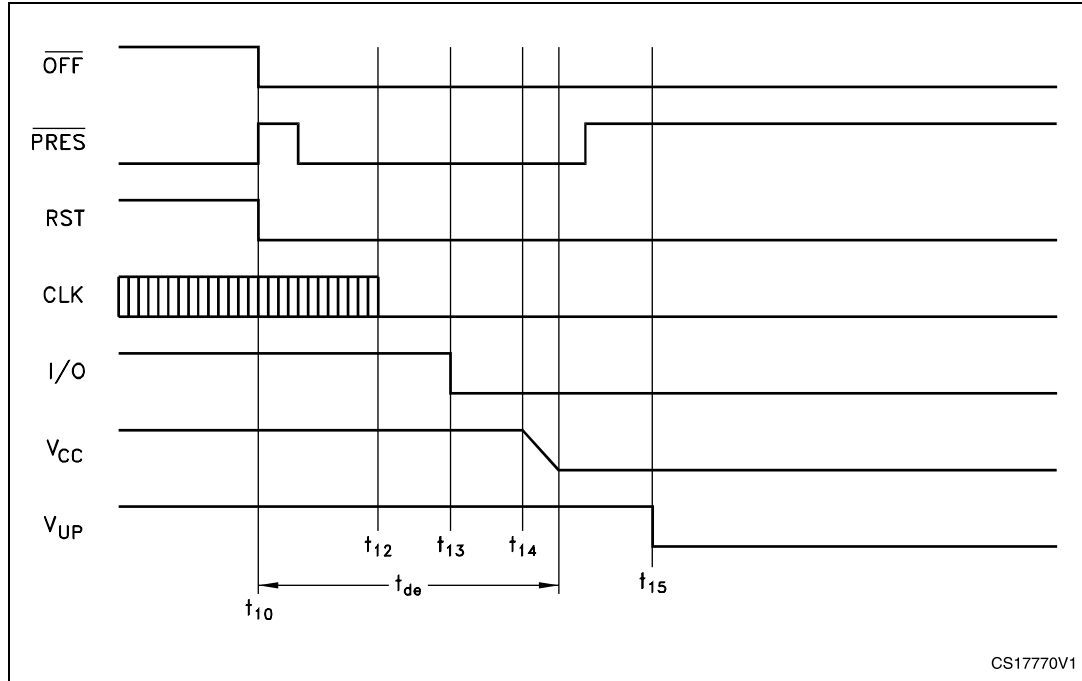


Figure 9. Emergency deactivation sequence (card extraction)



### 6.11 V<sub>CC</sub> selection settings

The ST8024L supports three smartcard V<sub>CC</sub> voltages: 1.8 V, 3 V, and 5 V. The V<sub>CC</sub> selection is controlled by the 1.8V and 5V/3V signals as shown in Table 23. The 1.8V signal has priority over the 5V/3V. When the 1.8 V pin is taken high, V<sub>CC</sub> is 1.8 V and it overrides any setting on the 5V/3V pin.

When the 1.8V pin is taken low, the 5V/3V pin selects the 5 V or 3 V V<sub>CC</sub>. If the 5V/3V pin is taken high, then V<sub>CC</sub> is 5 V, and if the 5V/3V pin is taken low then V<sub>CC</sub> is 3 V.

Table 23. V<sub>CC</sub> selection settings

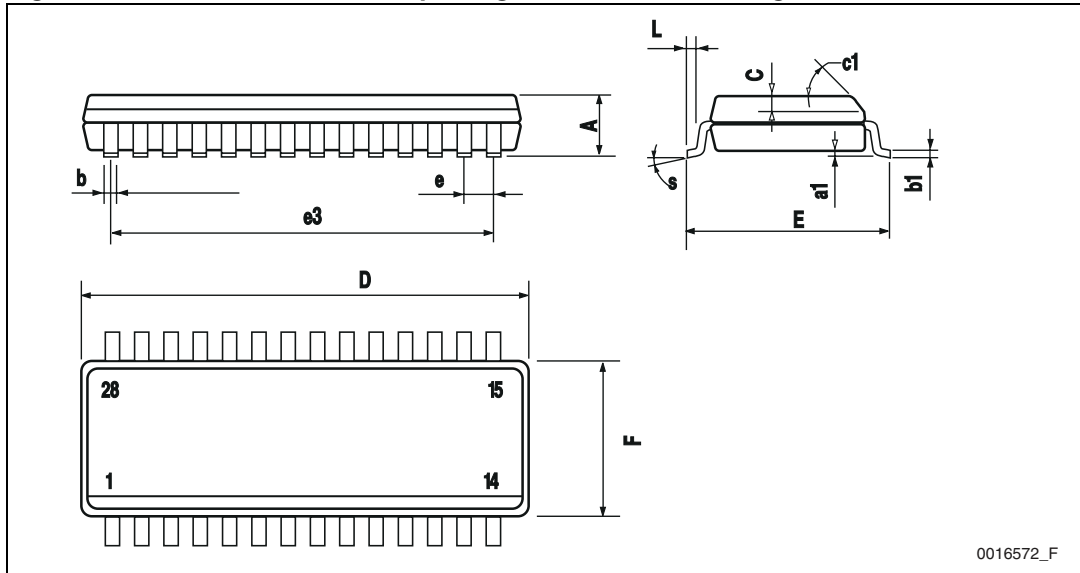
5V/3V pin	1.8V pin	V <sub>CC</sub> output
0	0	3 V
1	0	5 V
x	1	1.8 V



## 8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

Figure 11. SO-28 small outline, package mechanical drawing



0016572\_F

Table 24. SO-28 small outline, package mechanical data

Symbol	Dimensions					
	mm.			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			2.65			0.104
a1	0.1		0.3	0.004		0.012
b	0.35		0.49	0.014		0.019
b1	0.23		0.32	0.009		0.012
C		0.5			0.020	
c1	45° (typ.)					
D	17.70		18.10	0.697		0.713
E	10.00		10.65	0.393		0.419
e		1.27			0.050	
e3		16.51			0.650	
F	7.40		7.60	0.291		0.300
L	0.50		1.27	0.020		0.050
S	8° (max.)					

Figure 12. TSSOP-20 package mechanical drawing

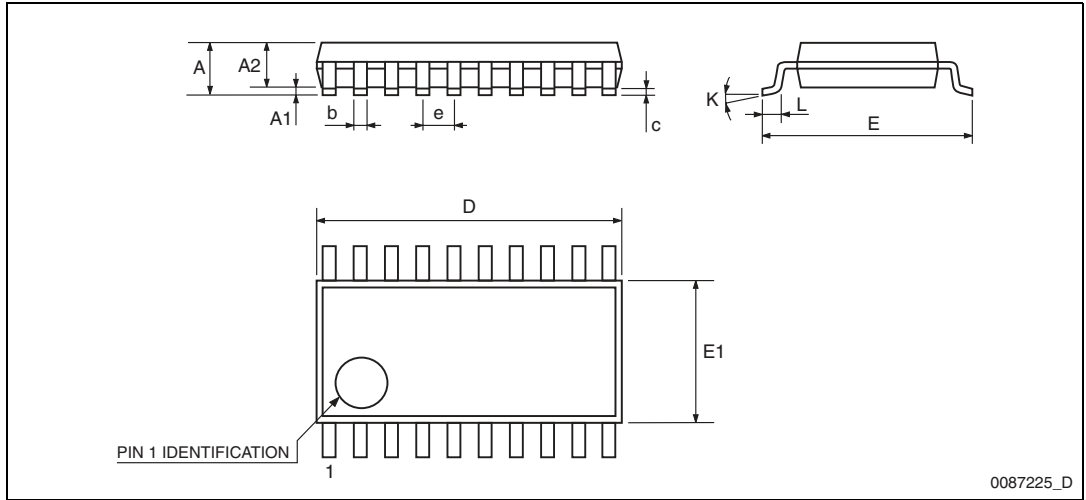
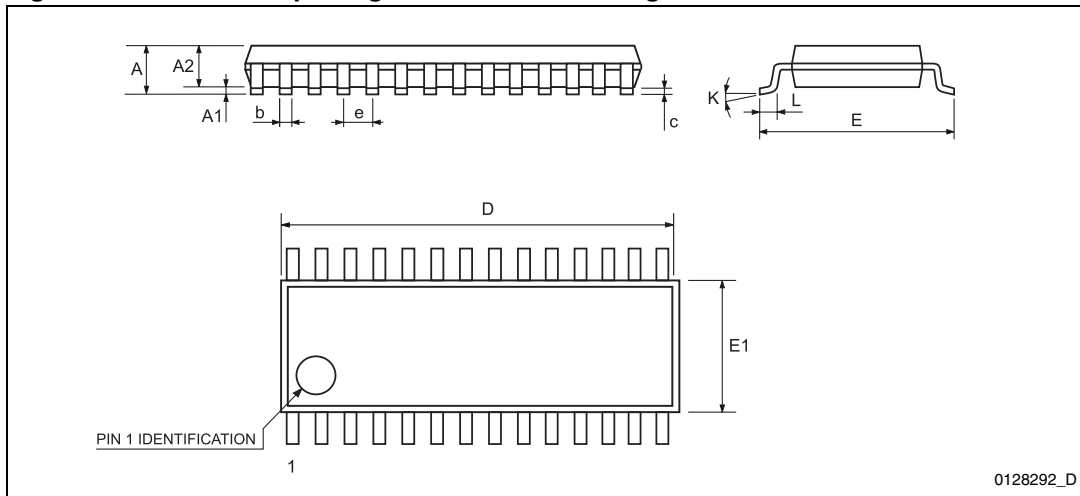


Table 25. TSSOP-20 package mechanical data

Symbol	Dimensions					
	mm.			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0079
D	6.4	6.5	6.6	0.252	0.256	0.260
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030

Figure 13. TSSOP-28 package mechanical drawing



0128292\_D

Table 26. TSSOP-28 package mechanical data

Symbol	Dimensions					
	mm.			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0079
D	9.6	9.7	9.8	0.378	0.382	0.386
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030

Figure 14. SO-28 tape and reel schematic

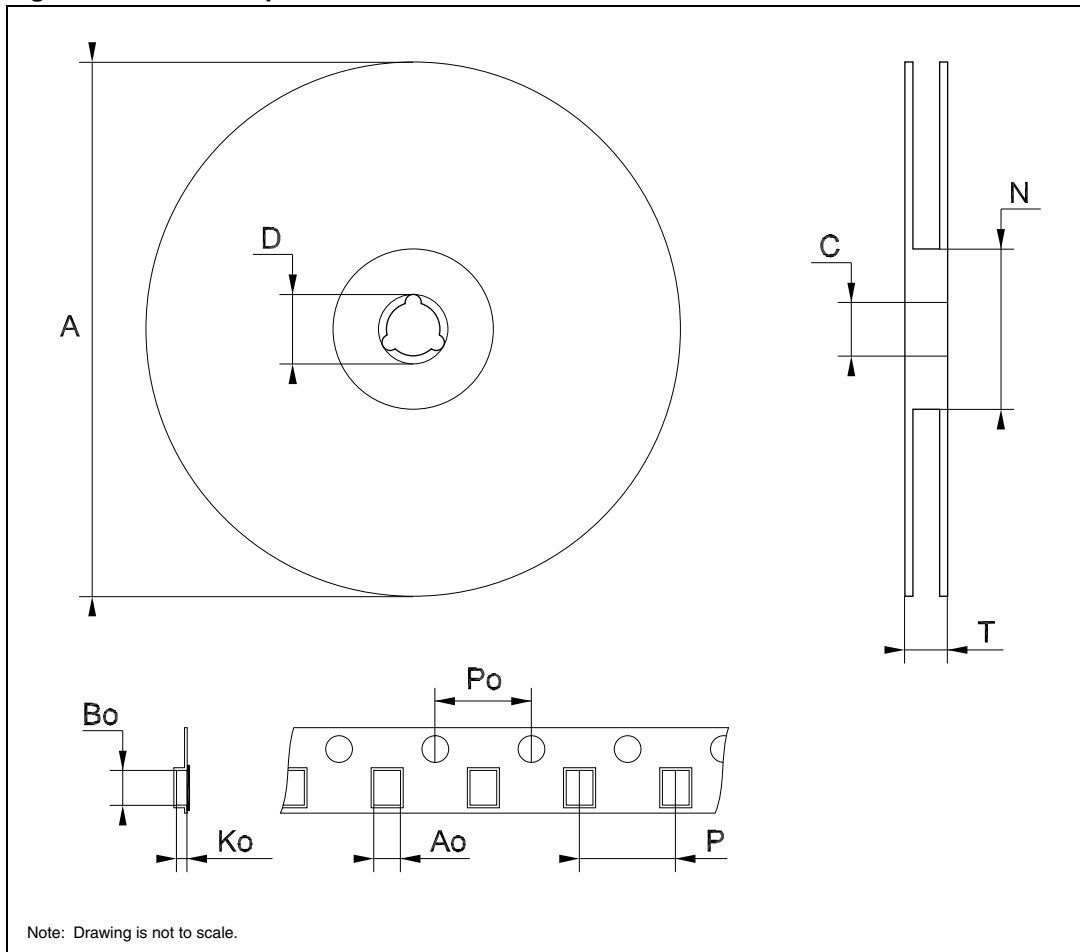


Table 27. SO-28 tape and reel mechanical data

Symbol	Dimensions					
	mm.			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			30.4			1.197
A <sub>O</sub>	10.8		11.0	0.425		0.433
B <sub>O</sub>	18.2		18.4	0.716		0.724
K <sub>O</sub>	2.9		3.1	0.114		0.122
P <sub>O</sub>	3.9		4.1	0.153		0.161
P	11.9		12.1	0.468		0.476

Figure 15. TSSOP-20 tape and reel schematic

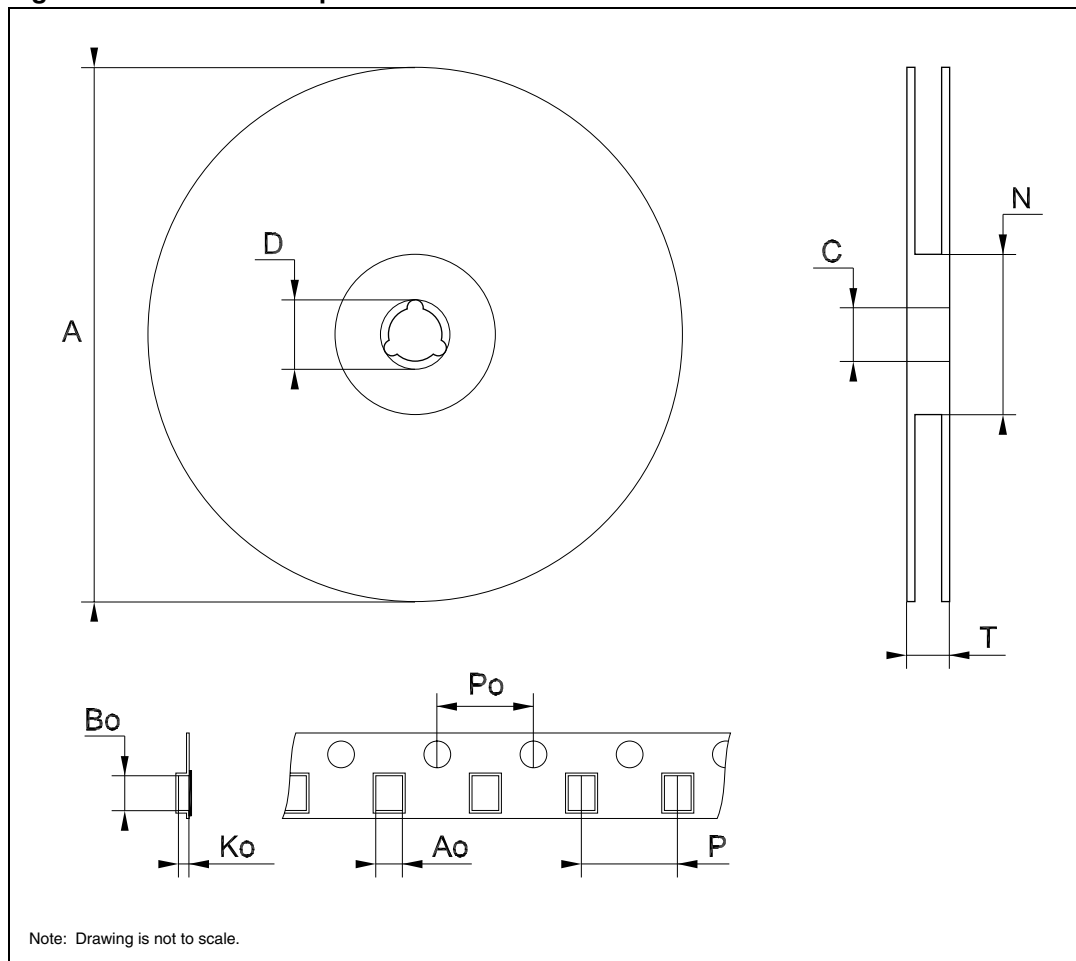


Table 28. TSSOP-20 tape and reel mechanical data

Symbol	Dimensions					
	mm.			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
A <sub>O</sub>	6.8		7	0.268		0.276
B <sub>O</sub>	6.9		7.1	0.272		0.280
K <sub>O</sub>	1.7		1.9	0.067		0.075
P <sub>O</sub>	3.9		4.1	0.153		0.161
P	11.9		12.1	0.468		0.476



Figure 16. TSSOP-28 tape and reel schematic

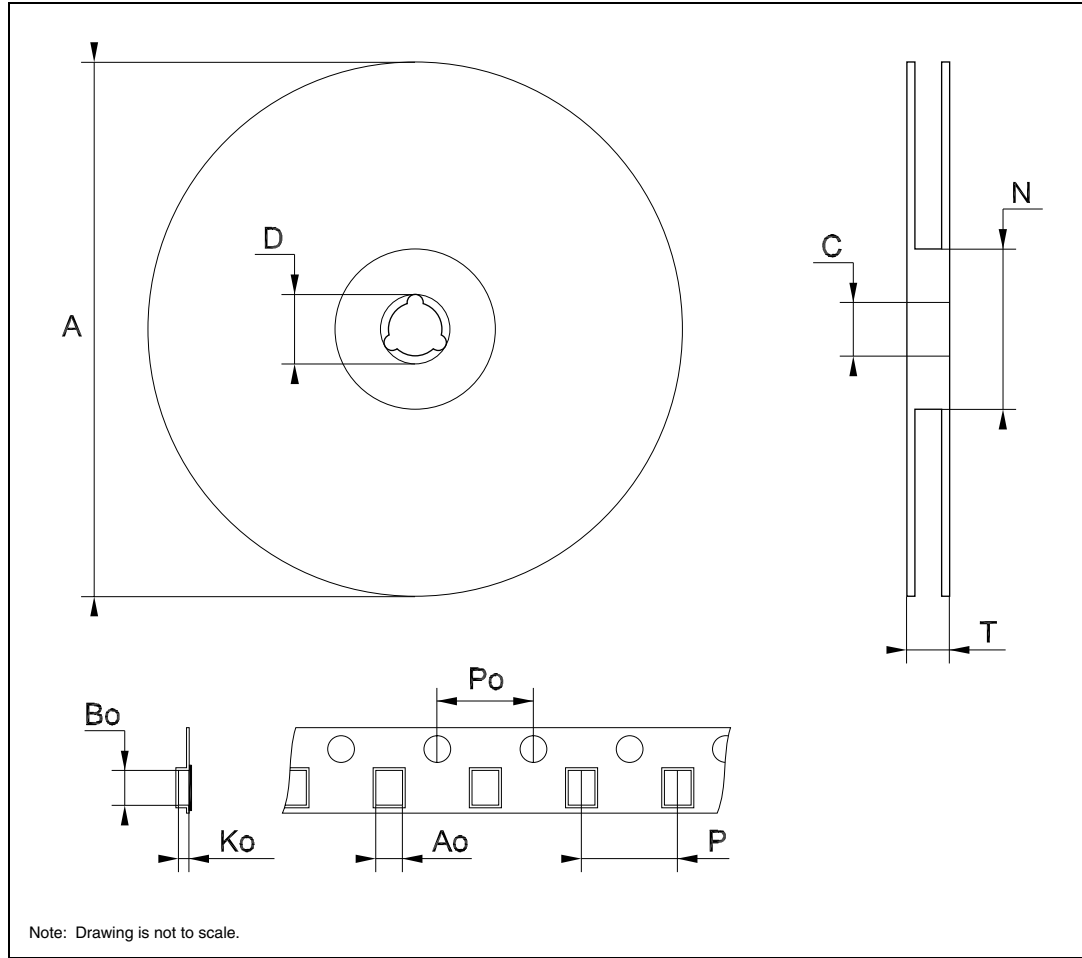


Table 29. TSSOP-28 tape and reel mechanical data

Symbol	Dimensions					
	mm.			inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
A <sub>O</sub>	6.8		7	0.268		0.276
B <sub>O</sub>	10.1		10.3	0.398		0.406
K <sub>O</sub>	1.7		1.9	0.067		0.075
P <sub>O</sub>	3.9		4.1	0.153		0.161
P	11.9		12.1	0.468		0.476

## 9 Revision history

**Table 30. Document revision history**

Date	Revision	Changes
19-Jul-2010	1	Initial release.
30-Jul-2010	2	Updated <i>Description</i> , <i>Table 6</i> .
27-Sep-2010	3	Updated <i>Features</i> , <i>Table 1</i> , <i>6</i> , <i>8</i> , <i>19</i> , <i>20</i> , <i>Section 6.1</i> , <i>Section 6.2.2</i> , <i>Section 6.6</i> , <i>Section 6.9</i> , footnotes of <i>Figure 10</i> .
09-Feb-2012	4	Added ST8024LACTR device, updated <i>Features</i> , <i>Table 1</i> , <i>Section 1: Description</i> (moved to page 5), <i>Figure 1</i> , <i>Figure 2</i> , <i>Table 2</i> , <i>Table 6</i> , <i>Table 8</i> , <i>Section 6.1</i> to <i>Section 6.3</i> , <i>Figure 10</i> and Disclaimer, minor text corrections throughout document.
04-May-2012	5	Updated <i>Figure 1</i> , <i>Table 2</i> , <i>Table 3</i> , <i>Table 6</i> , <i>Table 8</i> , <i>Table 14</i> , <i>Table 16</i> , <i>Table 17</i> , <i>Section 6.1</i> , moved notes from <i>Section 5</i> below <i>Table 3</i> , <i>Table 8</i> , <i>Table 15</i> , <i>Table 16</i> , <i>Table 17</i> , minor text corrections throughout document.

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